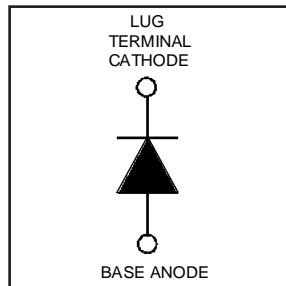


# HFA135NH40R

Ultrafast, Soft Recovery Diode

## Features

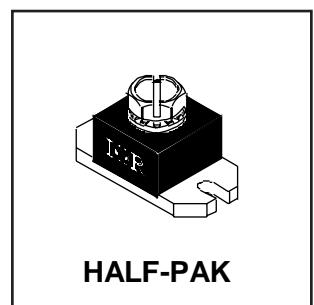
- Reduced RFI and EMI
- Reduced Snubbing
- Extensive Characterization of Recovery Parameters



$V_R = 400V$
$I_F(\text{typ.})^{\circledcirc} = 1V$
$I_{F(AV)} = 135A$
$Q_{rr}(\text{typ.}) = 290nC$
$I_{RRM}(\text{typ.}) = 7.5A$
$t_{rr}(\text{typ.}) = 50ns$
$dI_{(rec)M}/dt (\text{typ.})^{\circledcirc} = 270A/\mu s$

## Description

HEXFRED™ diodes are optimized to reduce losses and EMI/RFI in high frequency power conditioning systems. An extensive characterization of the recovery behavior for different values of current, temperature and  $di/dt$  simplifies the calculations of losses in the operating conditions. The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for power converters, motors drives and other applications where switching losses are significant portion of the total losses.



HALF-PAK

## Absolute Maximum Ratings (per Leg)

	Parameter	Max.	Units
$V_R$	Cathode-to-Anode Voltage	400	V
$I_F @ T_C = 25^\circ C$	Continuous Forward Current	211	A
$I_F @ T_C = 100^\circ C$	Continuous Forward Current	103	
$I_{FSM}$	Single Pulse Forward Current ①	900	
$E_{AS}$	Non-Repetitive Avalanche Energy ②	1.4	mJ
$P_D @ T_C = 25^\circ C$	Maximum Power Dissipation	379	W
$P_D @ T_C = 100^\circ C$	Maximum Power Dissipation	152	
$T_J$ $T_{STG}$	Operating Junction and Storage Temperature Range	-55 to +150	°C

## Thermal - Mechanical Characteristics

	Parameter	Min.	Typ.	Max.	Units
$R_{thJC}$	Junction-to-Case	—	—	0.33	°C/W
$R_{thCS}$	Case-to-Sink, Flat, Greased Surface	—	0.15	—	K/W
Wt	Weight	—	26 (0.9)	—	g (oz)
	Mounting Torque ④	15 (1.7)	—	25 (2.8)	lbf·in (N·m)
	Terminal Torque	30 (3.4)	—	40 (4.6)	
	Vertical Pull	—	—	80	lbf·in
	2 inch Lever Pull	—	—	40	

Note: ① Limited by junction temperature

②  $L = 100\mu H$ , duty cycle limited by max  $T_J$

③  $125^\circ C$

④ Mounting surface must be smooth, flat, free of burrs or other protrusions. Apply a thin even film of thermal grease to mounting surface. Gradually tighten each mounting bolt in 5-10 lbf·in steps until desired or maximum torque limits are reached. Module

# HFA135NH40R

PD-2.455 rev. B 03/99

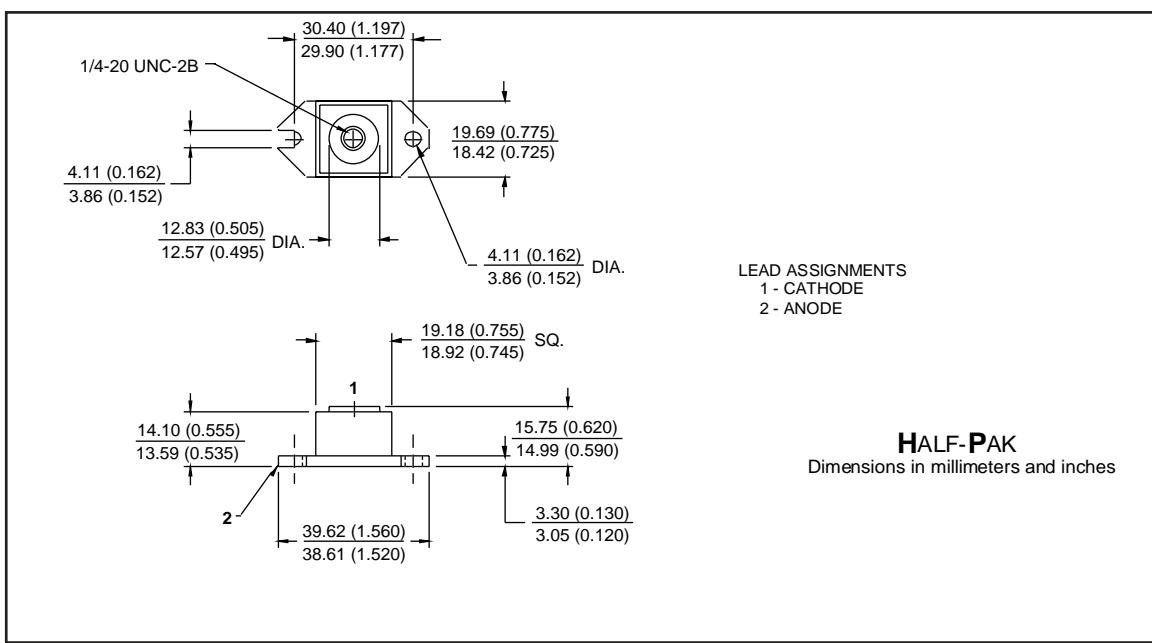
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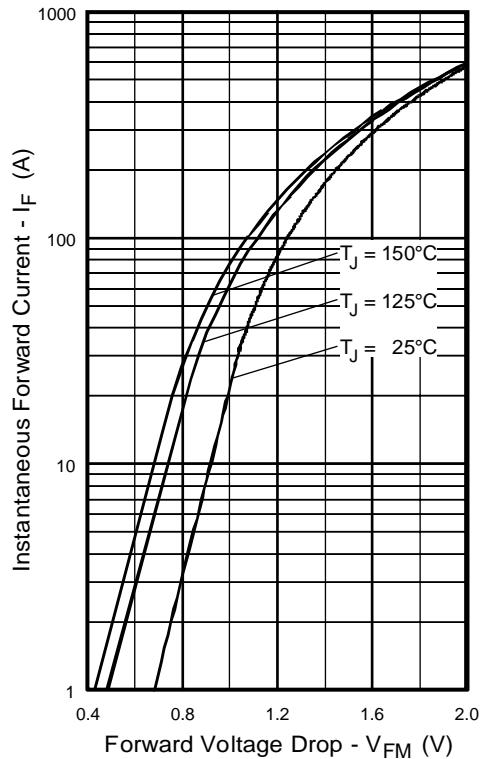
## Electrical Characteristics (per Leg) @ $T_J = 25^\circ\text{C}$ (unless otherwise specified)

Parameter	Min.	Typ.	Max.	Units	Test Conditions
$V_{BR}$ Cathode Anode Breakdown Voltage	400	—	—	V	$I_R = 100\mu\text{A}$
$V_{FM}$ Max Forward Voltage See Fig. 1	—	1.1	1.3	V	$I_F = 135\text{A}$
	—	1.4	1.6		$I_F = 270\text{A}$
	—	1.0	1.2		$I_F = 135\text{A}, T_J = 125^\circ\text{C}$
$I_{RM}$ Max Reverse Leakage Current See Fig. 2	—	1.5	9.0	$\mu\text{A}$	$V_R = V_R$ Rated
	—	2.3	12	mA	$T_J = 125^\circ\text{C}, V_R = 320\text{V}$
$C_T$ Junction Capacitance See Fig. 3	—	280	380	pF	$V_R = 200\text{V}$
$L_S$ Series Inductance	—	6.0	—	nH	From top of terminal hole to mounting plane

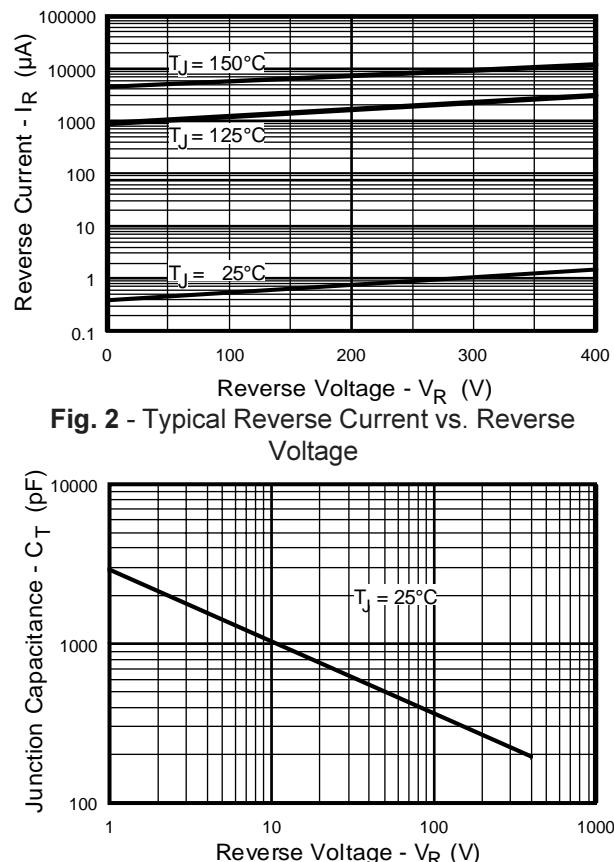
## Dynamic Recovery Characteristics (per Leg) @ $T_J = 25^\circ\text{C}$ (unless otherwise specified)

Parameter	Min.	Typ.	Max.	Units	Test Conditions
$t_{rr}$ Reverse Recovery Time	—	50	—	ns	$I_F = 1.0\text{A}, dI_F/dt = 200\text{A}/\mu\text{s}, V_R = 30\text{V}$
$t_{rr1}$ See Fig. 5	—	77	120		$T_J = 25^\circ\text{C}$
$t_{rr2}$	—	290	440		$T_J = 125^\circ\text{C}$
$I_{RRM1}$ Peak Recovery Current	—	7.5	14	A	$T_J = 25^\circ\text{C}$
$I_{RRM2}$ See Fig. 6	—	16	30		$T_J = 125^\circ\text{C}$
$Q_{rr1}$ Reverse Recovery Charge	—	290	780		$T_J = 25^\circ\text{C}$
$Q_{rr2}$ See Fig. 7	—	2300	6300	nC	$T_J = 125^\circ\text{C}$
$dI_{(rec)M}/dt_1$ Peak Rate of Fall of Recovery Current	—	320	—		$T_J = 25^\circ\text{C}$
$dI_{(rec)M}/dt_2$ During $t_b$ See Fig. 8	—	270	—		$T_J = 125^\circ\text{C}$

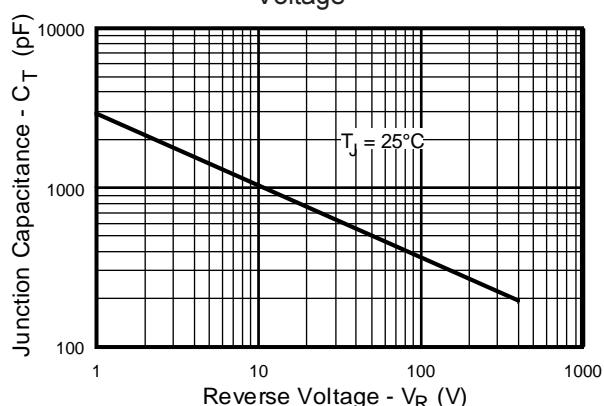




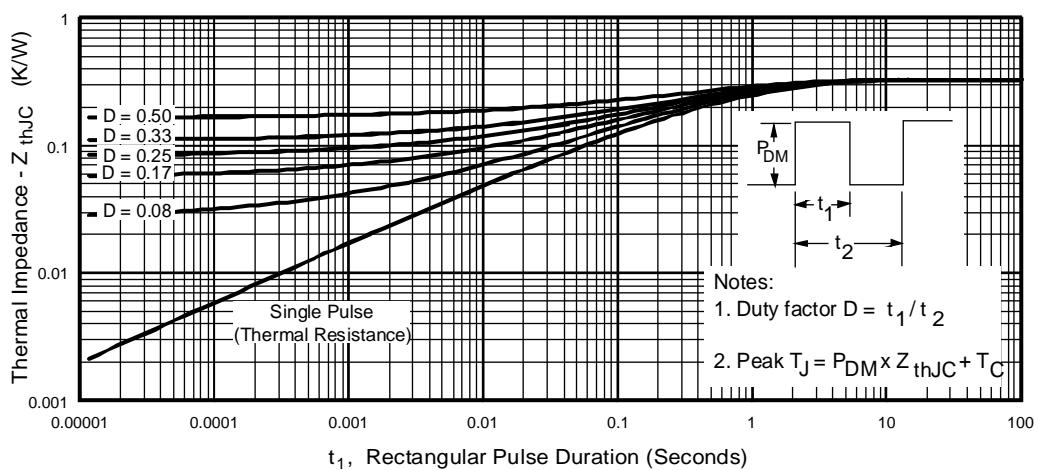
**Fig. 1 - Maximum Forward Voltage Drop vs. Instantaneous Forward Current**



**Fig. 2 - Typical Reverse Current vs. Reverse Voltage**



**Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage**

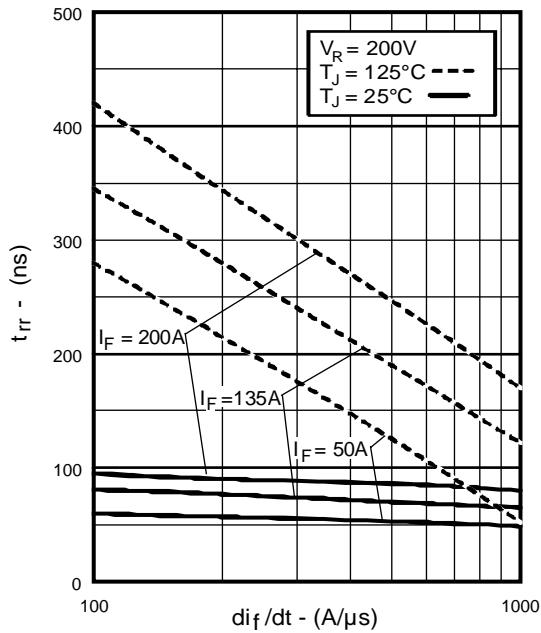


**Fig. 4 - Maximum Thermal Impedance  $Z_{thjc}$  Characteristics**

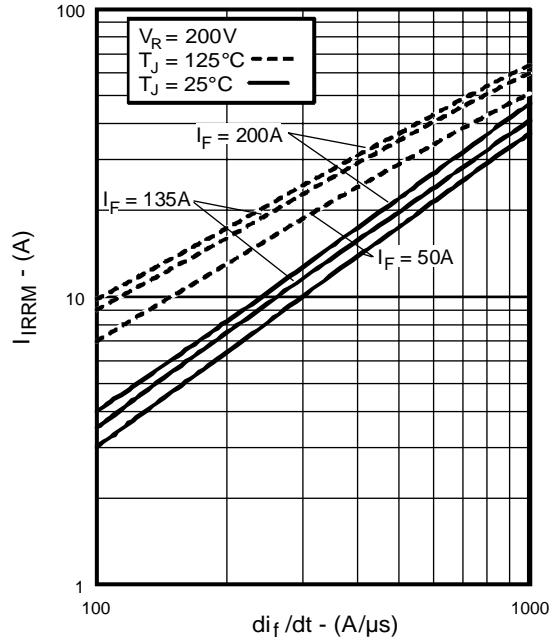
# HFA135NH40R

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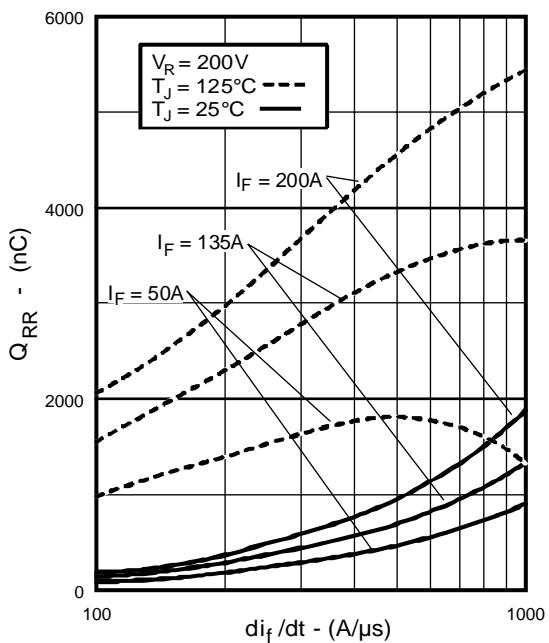
International  
**IR** Rectifier



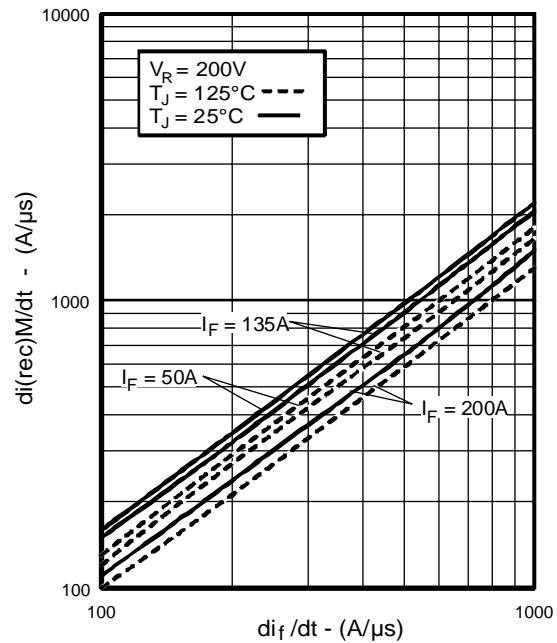
**Fig. 5** - Typical Reverse Recovery vs.  $di_f/dt$



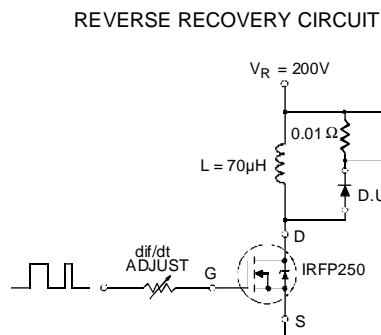
**Fig. 6** - Typical Recovery Current vs.  $di_f/dt$



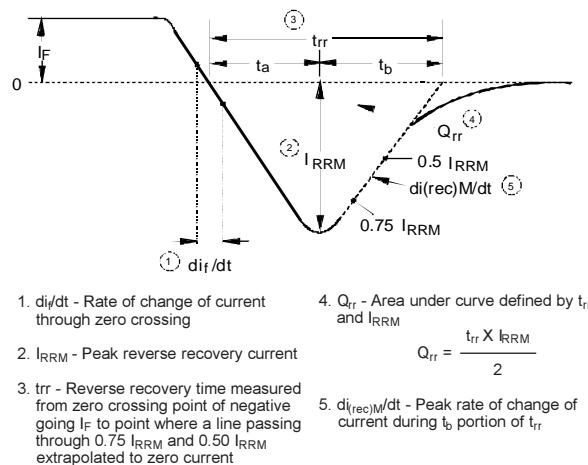
**Fig. 7** - Typical Stored Charge vs.  $di_f/dt$



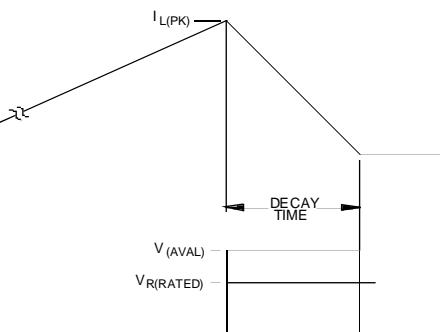
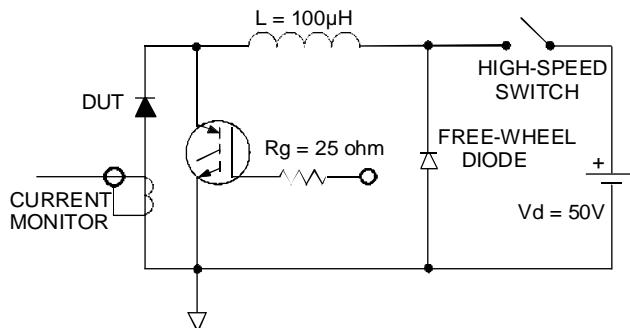
**Fig. 8** - Typical  $dI_{rec}/dt$  vs.  $di_f/dt$



**Fig. 9 - Reverse Recovery Parameter Test Circuit**



**Fig. 10 - Reverse Recovery Waveform and Definitions**



**Fig. 11 - Avalanche Test Circuit and Waveforms**

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